74AUP1G132

Low-power 2-input NAND Schmitt trigger

Rev. 8 — 14 January 2022

Product data sheet

1. General description

The 74AUP1G132 is a single 2-input NAND gate with Schmitt-trigger inputs. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- · CMOS low power dissipation
- · High noise immunity
- Overvoltage tolerant inputs to 3.6 V
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- · Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Applications

- · Wave and pulse shaper
- Astable multivibrator
- Monostable multivibrator.



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4. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AUP1G132GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1
74AUP1G132GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886
74AUP1G132GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115
74AUP1G132GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202
74AUP1G132GX	-40 °C to +125 °C	X2SON5	plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.32 mm	SOT1226-3

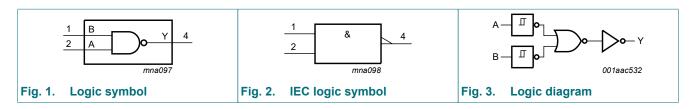
5. Marking

Table 2. Marking

Table 21 marking	
Type number	Marking code [1]
74AUP1G132GW	аЕ
74AUP1G132GM	аЕ
74AUP1G132GN	аЕ
74AUP1G132GS	аЕ
74AUP1G132GX	аЕ

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

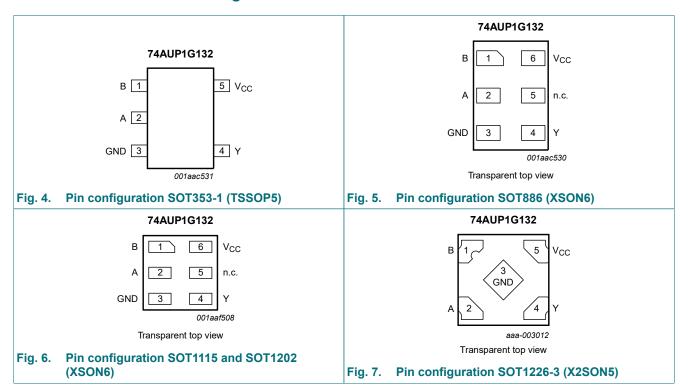
6. Functional diagram



Low-power 2-input NAND Schmitt trigger

7. Pinning information

7.1. Pinning



7.2. Pin description

Table 3. Pin description

Symbol	Pin	Pin				
	TSSOP5 and X2SON5	XSON6				
В	1	1	data input			
A	2	2	data input			
GND	3	3	ground (0 V)			
Υ	4	4	data output			
n.c.	-	5	not connected			
V _{CC}	5	6	supply voltage			

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8. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

Input	Output	
A	В	Υ
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
Io	output current	V _O = 0 V to V _{CC}	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ [2]	-	250	mW

^[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C

^[2] For SOT353-1 (TSSOP5) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT886 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: Ptot derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT1226-3 (X2SON5) package: Ptot derates linearly with 3.0 mW/K above 67 °C.

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11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	25 °C			<u>'</u>		
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				\Box
		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		$I_O = 20 \mu A; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
l _l	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.1	μΑ
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$	-	-	±0.2	μA
Δl _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.2	μΑ
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.5	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	40	μΑ
Cı	input capacitance	$V_I = GND \text{ or } V_{CC}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	1.1	-	pF
Co	output capacitance	V _O = GND; V _{CC} = 0 V	-	1.7	-	pF
T _{amb} = -	40 °C to +85 °C			1		
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		$I_O = 20 \mu A; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.5	μΑ
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.6	μΑ
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	0.9	μΑ
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	50	μΑ
T _{amb} = -4	40 °C to +125 °C					
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I_{O} = -2.7 mA; V_{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		$I_O = 20 \mu A; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		$I_O = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.75	μΑ
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$	-	-	±0.75	μΑ
ΔI_{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.75	μΑ
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	75	μΑ

^[1] One input at $V_{\mbox{\footnotesize CC}}$ - 0.6 V, other input at $V_{\mbox{\footnotesize CC}}$ or GND.

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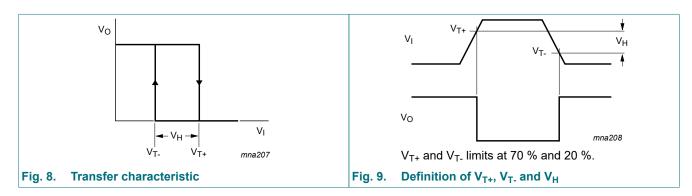
11.1. Transfer characteristics

Table 8. Transfer characteristics

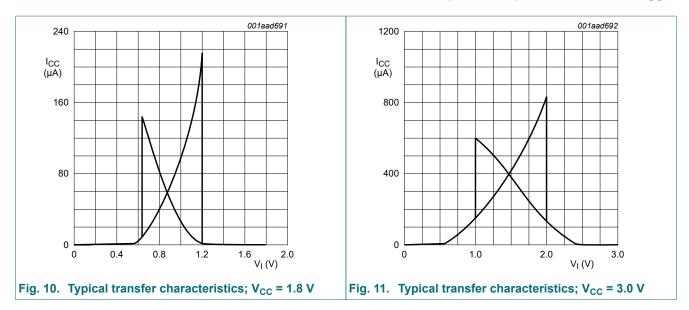
Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 13.

Symbol	Parameter	Conditions		25 °C			°C to		°C to 5 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
V _{T+}	positive-going	see Fig. 8 and Fig. 9								
	threshold voltage	V _{CC} = 0.8 V	0.30	-	0.60	0.30	0.60	0.30	0.62	V
	Voltage	V _{CC} = 1.1 V	0.53	-	0.90	0.53	0.90	0.53	0.92	V
		V _{CC} = 1.4 V	0.74	-	1.11	0.74	1.11	0.74	1.13	V
		V _{CC} = 1.65 V	0.91	-	1.29	0.91	1.29	0.91	1.31	V
		V _{CC} = 2.3 V	1.37	-	1.77	1.37	1.77	1.37	1.80	V
		V _{CC} = 3.0 V	1.88	-	2.29	1.88	2.29	1.88	2.32	V
V _{T-}	negative-going threshold voltage	see Fig. 8 and Fig. 9								
		V _{CC} = 0.8 V	0.10	-	0.60	0.10	0.60	0.10	0.60	V
		V _{CC} = 1.1 V	0.26	-	0.65	0.26	0.65	0.26	0.65	V
		V _{CC} = 1.4 V	0.39	-	0.75	0.39	0.75	0.39	0.75	V
		V _{CC} = 1.65 V	0.47	-	0.84	0.47	0.84	0.47	0.84	V
		V _{CC} = 2.3 V	0.69	-	1.04	0.69	1.04	0.69	1.04	V
		V _{CC} = 3.0 V	0.88	-	1.24	0.88	1.24	0.88	1.24	V
V_{H}	hysteresis voltage	(V _{T+} - V _{T-}); see <u>Fig. 8</u> , <u>Fig. 9</u> , <u>Fig. 10</u> and <u>Fig. 11</u>								
		V _{CC} = 0.8 V	0.07	-	0.50	0.07	0.50	0.07	0.50	V
		V _{CC} = 1.1 V	0.08	-	0.46	0.08	0.46	0.08	0.46	V
		V _{CC} = 1.4 V	0.18	-	0.56	0.18	0.56	0.18	0.56	V
		V _{CC} = 1.65 V	0.27	-	0.66	0.27	0.66	0.27	0.66	V
		V _{CC} = 2.3 V	0.53	-	0.92	0.53	0.92	0.53	0.92	V
		V _{CC} = 3.0 V	0.79	-	1.31	0.79	1.31	0.79	1.31	V

11.2. Waveforms transfer characteristics



Low-power 2-input NAND Schmitt trigger



12. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 13.

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
C _L = 5 p	F								'	
t _{pd}	propagation	A or B to Y; see Fig. 12 [2]								
	delay	V _{CC} = 0.8 V	-	22.5	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	6.3	13.4	2.4	15.1	2.4	16.6	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.6	8.2	1.9	9.7	1.9	10.7	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.9	6.6	1.7	7.9	1.7	8.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	3.2	5.3	1.5	6.2	1.5	6.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.6	2.9	4.7	1.4	5.6	1.4	6.2	ns
C _L = 10	pF					•			'	
t _{pd}	propagation	A or B to Y; see <u>Fig. 12</u> [2]								
	delay	V _{CC} = 0.8 V	-	26.1	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.0	7.2	15.4	2.7	17.3	2.7	19.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.5	5.2	9.3	2.2	11.0	2.2	12.1	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.5	7.5	2.0	9.0	2.0	9.9	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.8	6.1	1.8	7.2	1.8	7.9	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.5	5.5	1.8	6.5	1.8	7.2	ns
C _L = 15	pF								<u>'</u>	
t _{pd}	propagation	A or B to Y; see <u>Fig. 12</u> [2]								
	delay	V _{CC} = 0.8 V	-	29.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.3	8.0	17.2	3.0	19.4	3.0	21.3	ns
		V _{CC} = 1.4 V to 1.6 V	2.8	5.8	10.4	2.5	12.3	2.5	13.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.6	5.0	8.3	2.3	10.0	2.3	11.0	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	4.2	6.7	2.1	7.9	2.1	8.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.2	3.9	6.1	2.0	7.3	2.0	8.0	ns

Low-power 2-input NAND Schmitt trigger

Symbol	Parameter	Conditions		25 °C		-40 °C to	+85 °C	-40 °C to	+125 °C	Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
C _L = 30	pF									
t _{pd}	propagation	A or B to Y; see Fig. 12 [2]								
	delay	V _{CC} = 0.8 V	-	39.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.3	10.2	22.6	3.8	25.4	3.8	27.9	ns
		V _{CC} = 1.4 V to 1.6 V	3.6	7.3	13.3	3.2	15.8	3.2	17.4	ns
		V _{CC} = 1.65 V to 1.95 V	3.2	6.3	10.6	2.9	12.8	2.9	14.1	ns
		V _{CC} = 2.3 V to 2.7 V	3.0	5.3	8.5	2.7	10.1	2.7	11.1	ns
		V _{CC} = 3.0 V to 3.6 V	2.8	5.0	7.8	2.7	9.2	2.7	10.1	ns
C _L = 5 p	F, 10 pF, 15 pF	and 30 pF				'				
C _{PD}	power dissipation	$f_i = 1 \text{ MHz};$ [3] $V_I = \text{GND to } V_{CC}$								
	capacitance	V _{CC} = 0.8 V	-	2.6	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.9	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.2	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.8	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.4	-	-	-	-	-	pF

- All typical values are measured at nominal V_{CC}.
- t_{pd} is the same as t_{PLH} and t_{PHL} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

12.1. Waveforms and test circuit

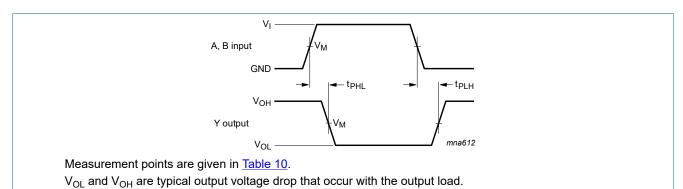


Fig. 12. The data input (A or B) to output (Y) propagation delays

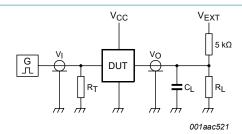
Table 10. Measurement points

Supply voltage	Output	Input				
V _{CC}	V _M	V _M	VI	$t_r = t_f$		
0.8 V to 3.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns		

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Test data is given in Table 11.

Definitions for test circuit:

R_L = Load resistance;

C_L = Load capacitance including jig and probe capacitance;

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator;

V_{EXT} = External voltage for measuring switching times.

Fig. 13. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load		V _{EXT}		
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}

[1] For measuring enable and disable times R_L = 5 k Ω . For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

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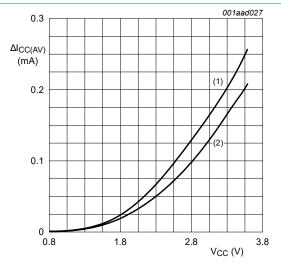
13. Application information

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

 $P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC} \text{ where:}$

- P_{add} = additional power dissipation (μW);
- f_i = input frequency (MHz);
- t_r = input rise time (ns); 10 % to 90 %;
- t_f = input fall time (ns); 90 % to 10 %;
- ΔI_{CC(AV)} = average additional supply current (µA).

Average $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in Fig. 14.



- (1) Positive-going edge.
- (2) Negative-going edge.

Linear change of V_I between 0.8 V and 2.0 V. All values given are typical, unless otherwise specified.

Fig. 14. Average I_{CC} as a function of V_{CC}

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14. Package outline

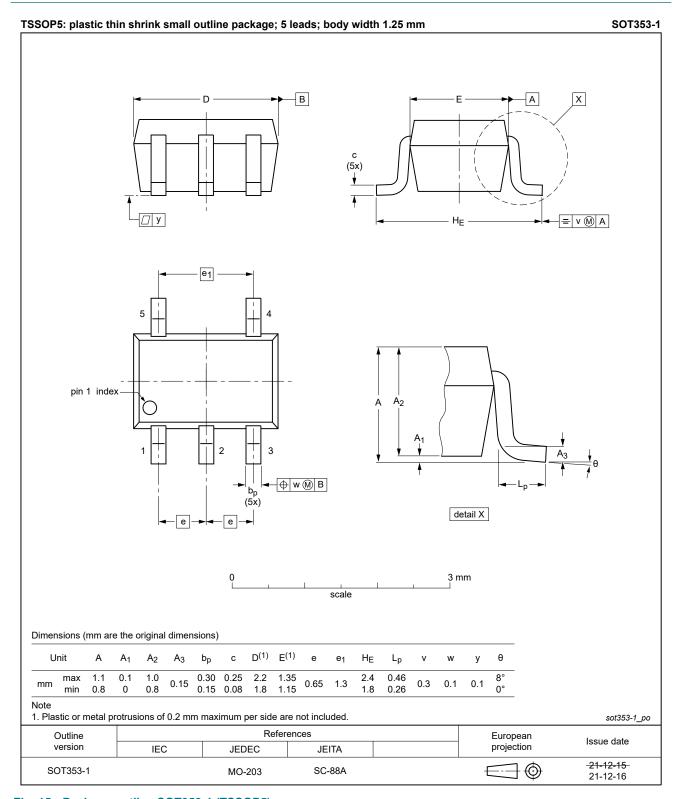


Fig. 15. Package outline SOT353-1 (TSSOP5)

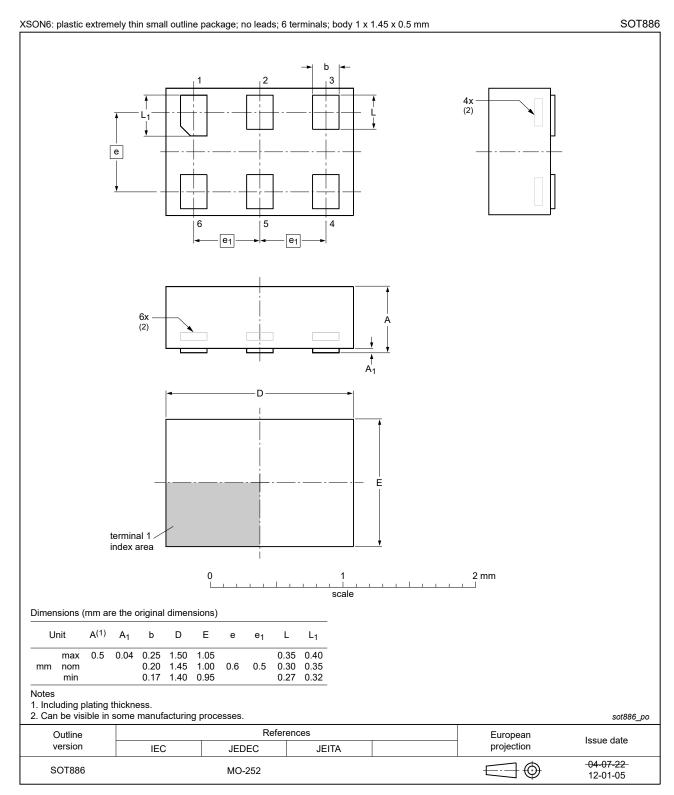


Fig. 16. Package outline SOT886 (XSON6)

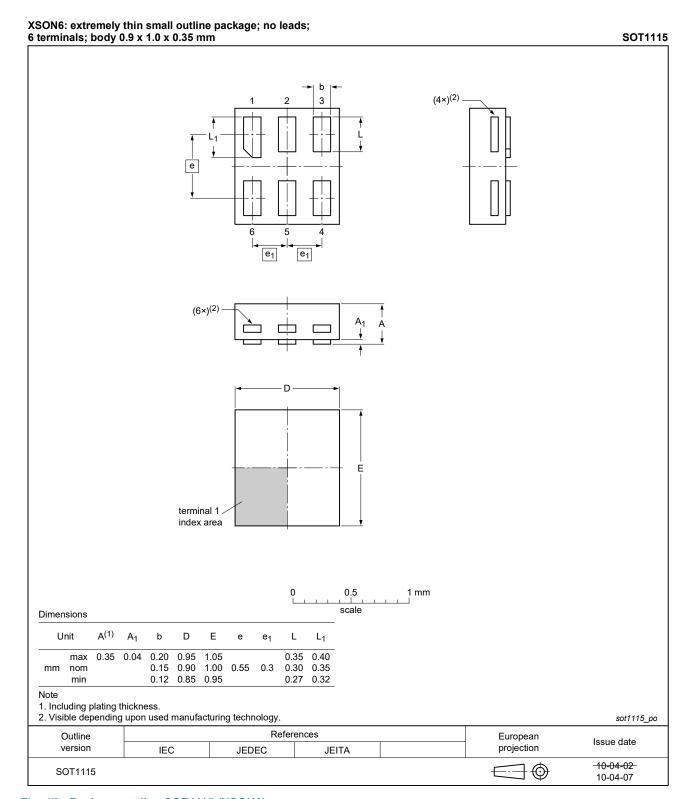


Fig. 17. Package outline SOT1115 (XSON6)

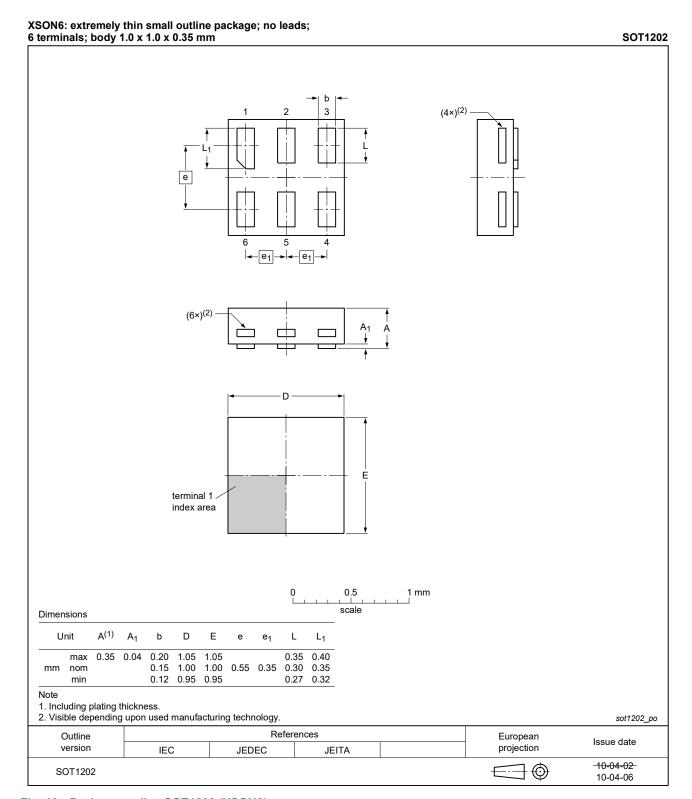


Fig. 18. Package outline SOT1202 (XSON6)

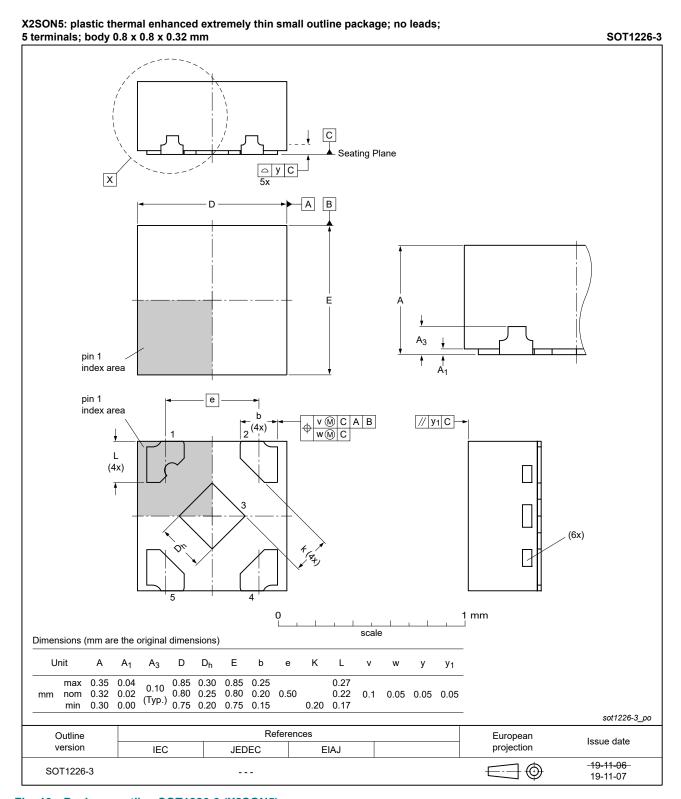


Fig. 19. Package outline SOT1226-3 (X2SON5)

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15. Abbreviations

Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

16. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74AUP1G132 v.8	20220114	Product data sheet	-	74AUP1G132 v.7		
Modifications:	• <u>Fig. 15</u> : Pac	Fig. 15: Package outline drawing for SOT353-1 (TSSOP5) has changed.				
74AUP1G132 v.7	20210709	Product data sheet	-	74AUP1G132 v.6		
Modifications:	Type numberSection 1 ar	 SOT1226 (X2SON5) package changed to SOT1226-3 (X2SON5) package. Type number 74AUP1G132GF (SOT891) removed. Section 1 and Section 2 updated. Table 5: Derating values for Ptot total power dissipation updated. 				
74AUP1G132 v.6	20190501	Product data sheet	-	74AUP1G132 v.5		
Modifications:	of Nexperia. • Legal texts I	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Pin configuration drawing SOT1226 (X2SON5) updated. 				
74AUP1G132 v.5	20120629	Product data sheet	-	74AUP1G132 v.4		
Modifications:	* *	 Added type number 74AUP1G132GX (SOT1226) Package outline drawing of SOT886 (<u>Fig. 16</u>) modified. 				
74AUP1G132 v.4	20111124	Product data sheet	-	74AUP1G132 v.3		
Modifications:	 Legal pages 	Legal pages updated.				
74AUP1G132 v.3	20101029	Product data sheet	-	74AUP1G132 v.2		
74AUP1G132 v.2	20090615	Product data sheet	-	74AUP1G132 v.1		
74AUP1G132 v.1	20061020	Product data sheet	-	-		

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17. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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